



Microsemi Corp.
The diode experts

**1N5518
thru
1N5546**

SCOTTSDALE, AZ
For more information call:
(602) 941-6300

FEATURES

- LOW ZENER NOISE SPECIFIED
- LOW ZENER IMPEDANCE
- LOW LEAKAGE CURRENT
- HERMETICALLY SEALED GLASS PACKAGE
- JAN/JANTX/JANTXV AVAILABLE ON 1N5518-1 THROUGH 1N5546B-1 PER MIL-S-19500/437

**LOW VOLTAGE
AVALANCHE
DIODES
DO-35**

MAXIMUM RATINGS

Operating Temperature: -65°C to +200°C
Storage Temperature: -65°C to +200°C

ELECTRICAL CHARACTERISTICS

†TA: 25°C unless otherwise noted. Based on dc measurements at thermal equilibrium.
VF: 1.8 Max @ IZT 200 mA for all types

JEDEC TYPE NO. (Note 1)	NOMINAL ZENER VOLTAGE VZ @ IZT VOLTS (Note 2)	TEST CURRENT IZT mAdc	MAX. ZENER IMPEDANCE ZzT @ IZT OHMS (Note 3)	MAX. REVERSE LEAKAGE CURRENT			B-C-D SUFFIX MAXIMUM DC ZENER CURRENT IZM mAdc (Note 5)	B-C-D SUFFIX MAX. NOISE DENSITY AT IZ = 250 µA ND (MICRO-VOLTS PER SQUARE ROOT CYCLE)	REGULATION FACTOR ΔVZ VOLTS (Note 6)	LOW VZ CURRENT IZL mA
				V _R - VOLTS						
				I _R µAdc (Note 4)	NON-A SUFFIX	B-C-D SUFFIX				
1N5518	3.3	20	26	5.0	0.90	1.0	115	0.5	0.90	2.0
1N5519	3.6	20	24	3.0	0.90	1.0	105	0.5	0.90	2.0
1N5520	3.9	20	22	1.0	0.90	1.0	98	0.5	0.90	2.0
1N5521	4.2	20	18	3.0	1.0	1.5	89	0.5	0.75	2.0
1N5522	4.7	10	22	2.0	1.5	2.0	81	0.5	0.60	1.0
1N5523	5.1	5.0	26	2.0	2.0	2.5	75	0.5	0.65	0.25
1N5524	5.6	3.0	30	2.0	3.0	3.5	68	1.0	0.30	0.25
1N5525	6.2	1.0	30	1.0	4.5	5.0	61	1.0	0.20	0.01
1N5526	6.8	1.0	30	1.0	5.5	6.2	56	1.0	0.10	0.01
1N5527	7.5	1.0	25	0.5	6.0	6.8	51	2.0	0.05	0.01
1N5528	8.2	1.0	40	0.5	6.5	7.5	46	4.0	0.05	0.01
1N5529	9.1	1.0	45	0.1	7.0	8.2	42	4.0	0.05	0.01
1N5530	10.0	1.0	60	0.05	8.0	9.1	38	4.0	0.10	0.01
1N5531	11.0	1.0	80	0.05	9.0	9.9	35	5.0	0.20	0.01
1N5532	12.0	1.0	100	0.05	9.5	10.8	32	10	0.20	0.01
1N5533	13.0	1.0	90	0.01	10.5	11.7	29	15	0.20	0.01
1N5534	14.0	1.0	100	0.01	11.5	12.6	27	20	0.20	0.01
1N5535	15.0	1.0	100	0.01	12	13.5	25	20	0.20	0.01
1N5536	16.0	1.0	100	0.01	13.0	14.4	24	20	0.20	0.01
1N5537	17.0	1.0	100	0.01	14.0	15.3	22	20	0.20	0.01
1N5538	18.0	1.0	100	0.01	15.0	16.2	21	20	0.20	0.01
1N5539	19.0	1.0	100	0.01	16.0	17.1	20	20	0.20	0.01
1N5540	20.0	1.0	100	0.01	17.0	18.0	19	20	0.20	0.01
1N5541	22.0	1.0	100	0.01	18.0	19.8	17	20	0.20	0.01
1N5542	24.0	1.0	100	0.01	20.0	21.6	16	20	0.30	0.01
1N5543	26.0	1.0	100	0.01	21.0	22.4	15	20	0.35	0.01
1N5544	28.0	1.0	100	0.01	23.0	25.2	14	20	0.40	0.01
1N5545	30.0	1.0	100	0.01	24.0	27.0	13	20	0.45	0.01
1N5546	33.0	1.0	100	0.01	28.0	29.7	12	20	0.50	0.01

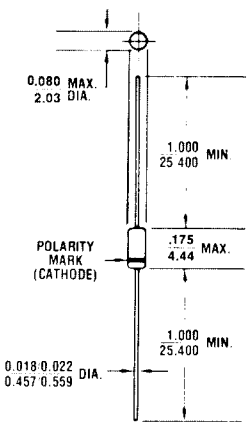


FIGURE 1

All dimensions in INCH
m. m.

NOTE 1 — TOLERANCE AND VOLTAGE DESIGNATION

The JEDEC type numbers shown are ± 20% with guaranteed limits for only VZ, IR, and VF. Units with A suffix are ± 10% with guaranteed limits for only VZ, IR, and VF. Units with guaranteed limits for all six parameters are indicated by a B suffix for ± 5.0% units, C suffix for ± 2.0% and D suffix for ± 1.0%.

NOTE 2 — ZENER (VZ) VOLTAGE MEASUREMENT

Nominal zener voltage is measured with the device junction in thermal equilibrium with ambient temperature of 25°C.

NOTE 3 — ZENER IMPEDANCE (Zz) DERIVATION

The zener impedance is derived from the 60 Hz ac voltage, which results when an ac current having an rms value equal to 10% of the dc zener current (IZT) is superimposed on IZT.

NOTE 4 — REVERSE LEAKAGE CURRENT (IR)

Reverse leakage currents are guaranteed and are measured at VR as shown on the table.

NOTE 5 — MAXIMUM REGULATOR CURRENT (IZM)

The maximum current shown is based on the maximum voltage of a 5.0% type unit, therefore, it applies only to the B suffix device. The actual IZM for any device may not exceed the value of 400 milliwatts divided by the actual VZ of the device.

NOTE 6 — MAXIMUM REGULATION FACTOR (ΔVZ)

ΔVZ is the maximum difference between VZ at IZT and VZ at IZL measured with the device junction in thermal equilibrium.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case. DO-35.

LEAD MATERIAL: Tinned copper clad steel.

MARKING: Body painted, alpha numeric.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

THERMAL RESISTANCE: 200°C/W (Typical) junction to lead at 0.375-inches from body. Metalurgically bonded DO-35s exhibit less than 100°C/Watt at zero distance from body.

1N5518 thru 1N5546 DO-35

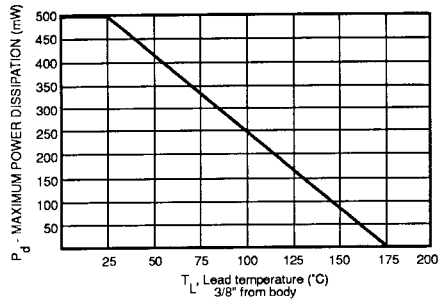


FIGURE 2
POWER-TEMPERATURE
DERATING CURVE

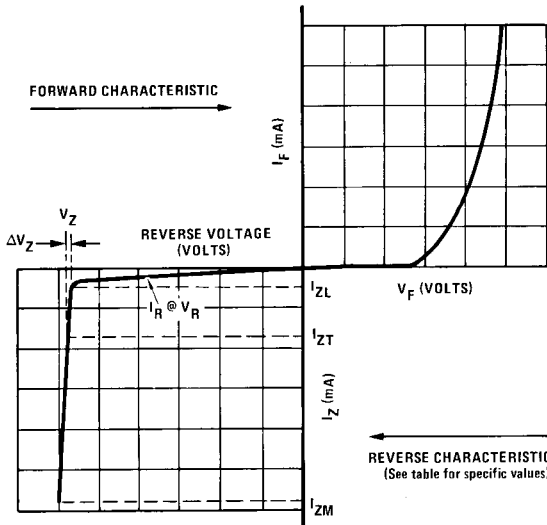
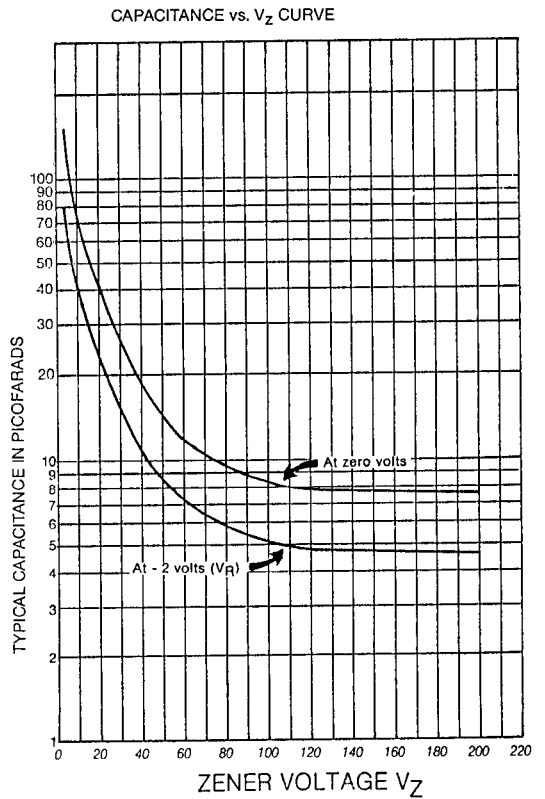


FIGURE 3
ZENER DIODE CHARACTERISTICS
AND SYMBOL IDENTIFICATION



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